

G3S06502H

## 650V/2A Silicon Carbide Power Schottky Barrier Diode

### **Features**

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

Key Characteristics			
V <sub>RRM</sub>	650	V	
I <sub>F,</sub> T <sub>c</sub> ≤158°C	2	Α	
Qc	8	nC	

### **Benefits**

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements



- ApplicationsSMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV







Part No.	Package Type	Marking
G3S06502H	TO-220F	G3S06502H

# **Maximum Ratings**

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$		650	
Surge Peak Reverse Voltage	$V_{RSM}$		650	V
DC Blocking Voltage	$V_{DC}$		650	
Continuous Forward Current	l <sub>F</sub>	$T_{C}$ =25 °C $T_{C}$ =125 °C $T_{C}$ =158 °C	7.9 4.2 2	А
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	$T_c$ =25°C, tp=10ms, Half Sine Wave, D=0.3	12	Α
Non-repetitive Peak Forward Surge Current	I <sub>FSM</sub>	$T_{C}$ =25 $^{\circ}$ C, tp=10ms , Half Sine Wave	30	Α
Power Dissipation	P <sub>TOT</sub>	T <sub>C</sub> =25℃ T <sub>C</sub> =110℃	33 14	W
Operating Junction	Tj		-55℃ to 175℃	$^{\circ}$
Storage Temperature	$T_{stg}$		-55℃ to 175℃	${\mathbb C}$
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in

# **Thermal Characteristics**

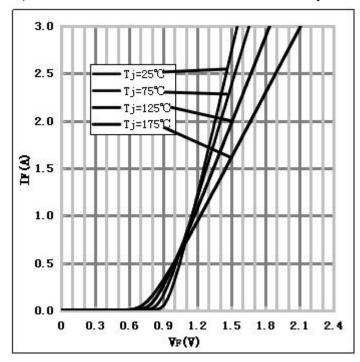
Daramatar	Symbol	Test Condition	Value	Unit
Parameter	Symbol	rest Condition	Typ. Unit	Onit
Thermal resistance from junction to case	R <sub>th JC</sub>		4.53	°C/W

## **Electrical Characteristics**

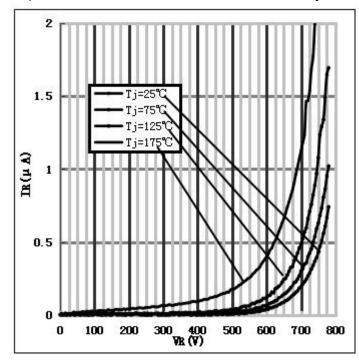
Doromotor	Symbol	Test Conditions	Numerical		l losit
Parameter		rest conditions	Тур.	Max.	Unit
Famurand Valtage	.,,	I <sub>F</sub> =2A, T <sub>j</sub> =25 ℃	1.37	1.7	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =2A, T <sub>j</sub> =175 ℃	1.67	2	V
Daviera Current		V <sub>R</sub> =650V, T <sub>j</sub> =25℃	0.04	50	
Reverse Current	l <sub>R</sub>	V <sub>R</sub> =650V, T <sub>j</sub> =175℃	0.4	100	μΑ
		$V_R=400V, T_j=150^{\circ}C$			
Total Capacitive Charge	$Q_{C}$	$Qc = \int_0^{VR} C(V)dV$	8	-	nC
	_	$V_R$ =0V, $T_j$ =25 $^{\circ}$ C, f=1MHZ	123	150	
Total Capacitance	C	$V_R$ =200V, $T_j$ =25 $^{\circ}$ C, f=1MHZ	12	20	pF
		$V_R$ =400V, $T_j$ =25 $^{\circ}$ C, f=1MHZ	13	30	

### **Performance Graphs**

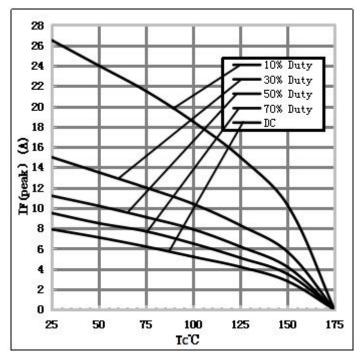
1) Forward IV characteristics as a function of Tj:



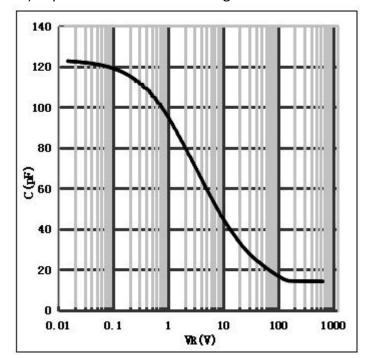
2) Reverse IV characteristics as a function of Tj:



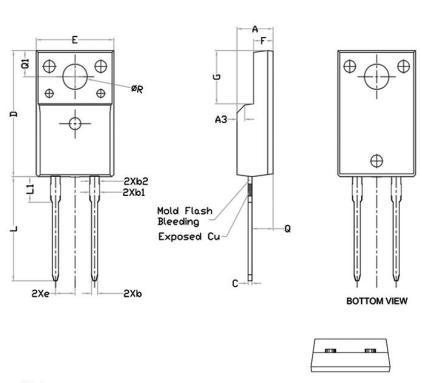
### 3) Current Derating:



### 4) Capacitance vs. reverse voltage:



Package TO-220F



单位: mm

	DIMENSIONS			
SYMBOL	Min.	Nom.	Max.	
Α	4.60	4.70	4.80	
b	0.70	0.80	0.91	
b1	1.20	1.30	1.47	
b2	1.10	1.20	1.30	
С	0.45	0.50	0.63	
D	15.80	15.87	15.97	
е	2.54			
E	10.00	10.10	10.30	
F	2.44	2.54	2.64	
G	6.50	6.70	6.90	
L	12.90	13.10	13.30	
L1	3.13	3.23	3.33	
Q	2.65	2.75	2.85	
Q1	3.20	3.30	3.40	
ΦR	3.08	3.18	3.28	

### Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash And Burrs Mold Flash Should Be Less Than 6 Mil.

**Note**: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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